



## BTA16/BTB16 Series 16A TRIACs

### DESCRIPTION:

High current density due to double mesa technology; SIPOS and Glass Passivation.

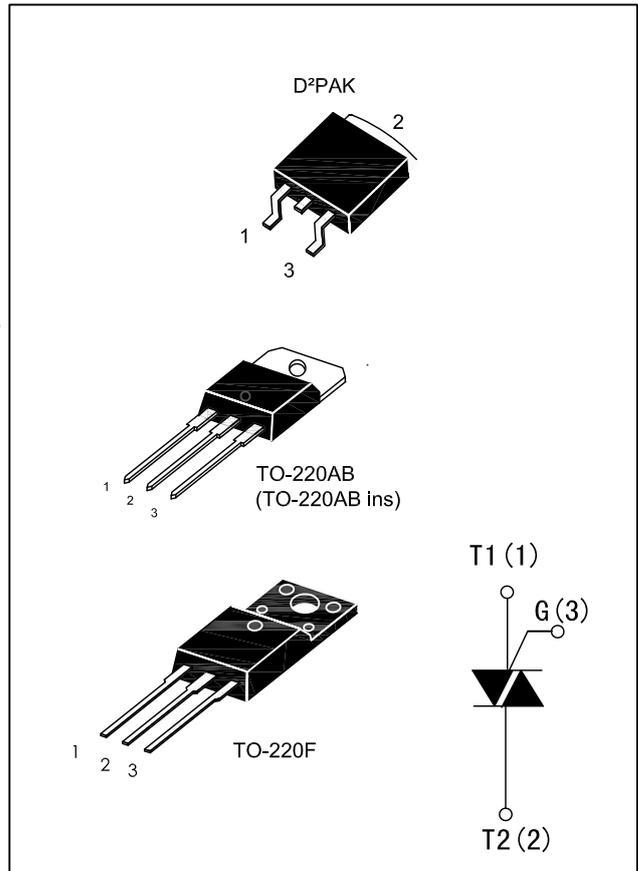
BTA16/BTB16 series triacs is suitable for general purpose AC switching. They can be used as an ON/OFF Function in applications such as static relays, heating regulation, induction motor starting circuits... or for phase control operation light dimmers, motorspeed controllers.

BTA16/BTB16- $\times\times\times$ SW、 $\times\times\times$ CW、 $\times\times\times$ BW are 3 Quadrants triacs, They are specially recommended for use on inductive loads.

TO-220ABins and TO-220F are isolated internally, they provides a 2500V RMS isolation voltage from all three terminals to external heatsink.

### MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	16	A
$V_{DRM}/V_{RRM}$	600 and 800	V
$V_{TM}$	$\leq 1.55$	V



### ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	Tstg	-40 to +150	°C
Operrrating junction temperature range	Tj	-40 to +125	°C
Repetitive Peak Off-state Voltage	Tj=25°C	VDRM	600and800
Repetitive Peak Reverse Voltage	Tj=25°C	VRRM	600and800
Non repetitive Surge Peak Off-state Voltage	tp=10ms, Tj=25°C	VDSM	700and900
Non repetitive Peak Reverse Voltage		VRSM	700and900
RMS on-state current (full sine wave)	D²PAK/TO-220AB Tc=100°C	IT(RMS)	16
	TO-220F Tc=78°C		
	TO-220AB Ins Tc=85°C		
Non repetitive surge peak on-state current (full cycle, Tj=25°C)	f = 60 Hz t=16.7ms	ITSM	168
	f = 50 Hz t=20ms		
I²t Value for fusing	tp=10ms	I²t	144
Critical rate of rise of on-state current IG=2×IGT, tr≤100 ns, f=120Hz, Tj=125°C		dl /dt	50
Peak gate current	tp=20us, Tj=125°C	IGM	4
Average gate power dissipation	Tj=125°C	PG(AV)	1

ELECTRICAL CHARACTERISTICS ( $T_j=25^\circ\text{C}$  unless otherwise specified)

## ● 3 Quadrants

Symbol	Test Condition	Quadrant		BTA16/BTB16			Unit
				SW	CW	BW	
$I_{GT}$	$V_D=12\text{V}$ $R_L=33\Omega$	I-II-III	MAX.	10	35	50	mA
$V_{GT}$		I-II-III	MAX.	1.3			V
$V_{GD}$	$V_D=V_{DRM}$ $R_L=3.3\text{K}\Omega$ $T_j=125^\circ\text{C}$	I-II-III	MIN.	0.2			V
$I_L$	$I_G=1.2I_{GT}$	I-III	MAX.	25	50	70	mA
		II	MAX.	30	60	80	mA
$I_H$	$I_T=500\text{mA}$		MAX.	15	35	50	mA
$dV/dt$	$V_D=67\%V_{DRM}$ gate open $T_j=125^\circ\text{C}$		MIN.	40	500	1000	$\text{V}/\mu\text{s}$
$(dI/dt)_c$	$(dV/dt)_c=0.1\text{V}/\mu\text{s}$ $T_j=125^\circ\text{C}$		MIN.	8.5	---	---	A/mS
	$(dV/dt)_c=10\text{V}/\mu\text{s}$ $T_j=125^\circ\text{C}$			3.0	---	---	
	Without snubber $T_j=125^\circ\text{C}$			---	8.5	14	

## ● 4 Quadrants

Symbol	Test Condition	Quadrant		BTA16/BTB16		Unit
				C	B	
$I_{GT}$	$V_D=12\text{V}$ $R_L=33\Omega$	I-II-III IV	MAX.	25 50	50 100	mA
$V_{GT}$		ALL	MAX.	1.3		V
$V_{GD}$	$V_D=V_{DRM}$ $R_L=3.3\text{K}\Omega$ $T_j=125^\circ\text{C}$	ALL	MIN.	0.2		V
$I_L$	$I_G=1.2I_{GT}$	I-III-IV	MAX.	40	60	mA
		II	MAX.	80	120	mA
$I_H$	$I_T=500\text{mA}$		MAX.	25	50	mA
$dV/dt$	$V_D=67\%V_{DRM}$ gate open $T_j=125^\circ\text{C}$		MIN.	200	400	$\text{V}/\mu\text{s}$
$(dI/dt)_c$	$(dI/dt)_c=7\text{A}/\text{ms}$ $T_j=125^\circ\text{C}$		MIN.	5	10	$\text{V}/\mu\text{s}$

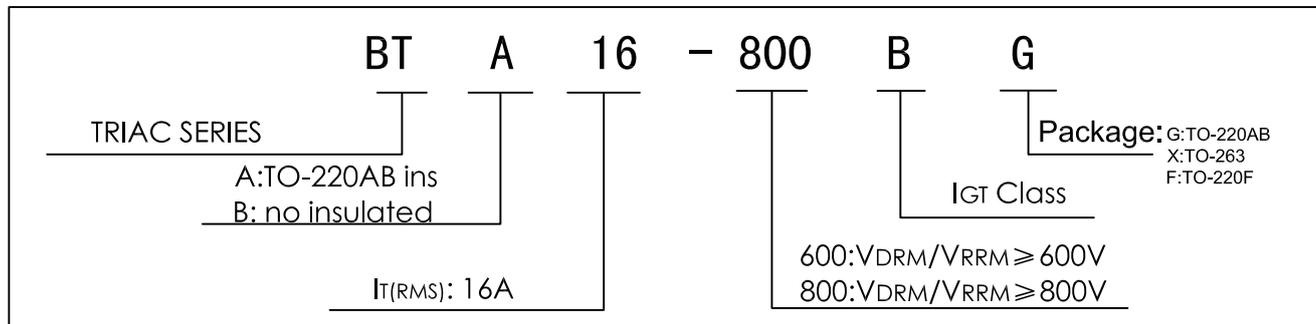
**STATIC CHARACTERISTICS**

Symbol	Parameter		Value(MAX.)	Unit
V <sub>TM</sub>	I <sub>TM</sub> =22.5A, t <sub>p</sub> =380μs	T <sub>j</sub> =25°C	1.55	V
I <sub>DRM</sub> I <sub>RRM</sub>	V <sub>D</sub> =V <sub>DRM</sub> V <sub>R</sub> =V <sub>RRM</sub>	T <sub>j</sub> =25°C	5	μA
		T <sub>j</sub> =125°C	2	mA

**THERMAL RESISTANCES**

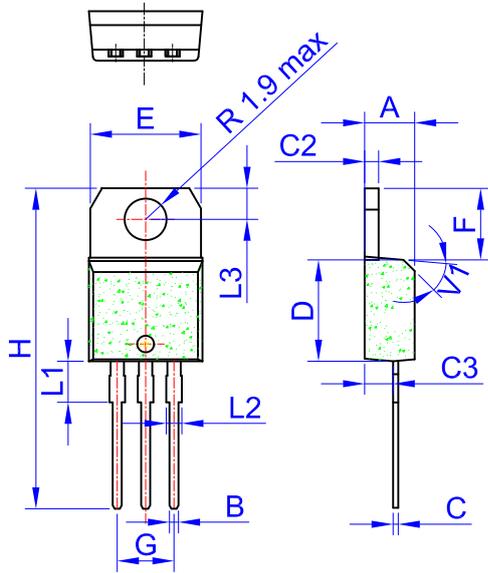
Symbol	Parameter		Value	Unit
R <sub>th</sub> ( J -C)	Junction to Case(AC)	D <sup>2</sup> PAK/TO-220AB	1.2	°C/W
		TO-220AB INS /TO-220F	2.1	

**ORDERING INFORMATION**



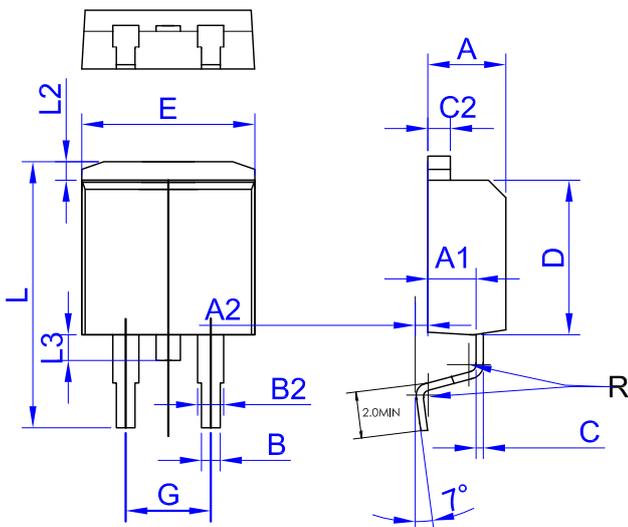
PACKAGE MECHANICAL DATA

TO-220AB



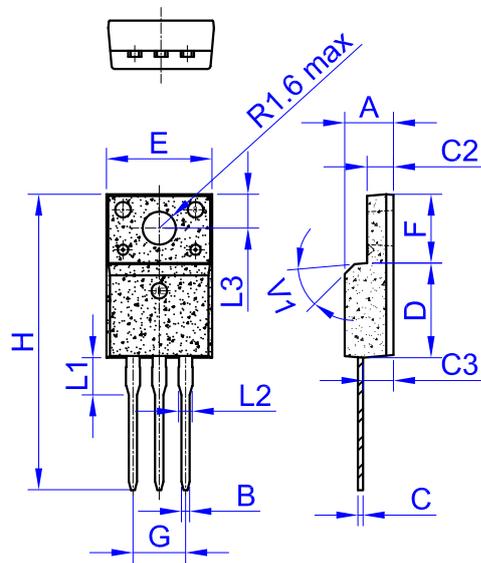
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.4		4.6	0.173		1.181
B	0.61		0.88	0.024		0.034
C	0.46		0.70	0.018		0.027
C2	1.23		1.32	0.048		0.051
C3	2.4		2.72	0.094		0.107
D	8.6		9.7	0.338		0.382
E	9.8		10.4	0.386		0.409
F	6.2		6.6	0.244		0.259
G	4.8		5.4	0.189		0.213
H	28.0		29.8	11.0		11.7
L1		3.75			0.147	
L2	1.14		1.7	0.044		0.066
L3	2.65		2.95	0.104		0.116
V1		40°			40°	

D<sup>2</sup> PAK



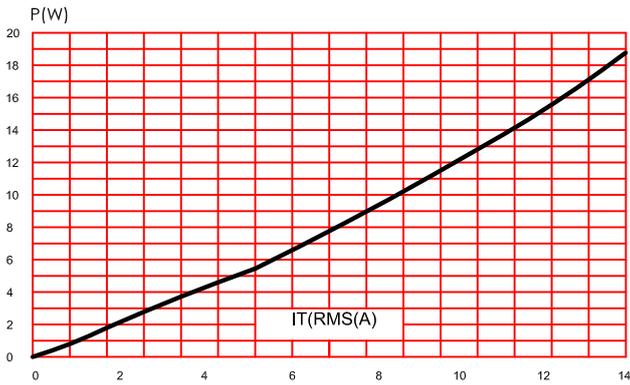
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.30		4.60	0.169		0.181
A1	2.49		2.69	0.098		0.106
A2	0.03		0.23	0.001		0.009
B	0.70		0.93	0.027		0.037
B2	1.25	1.40		0.048	0.055	
C	0.45		0.60	0.017		0.024
C2	1.21		1.36	0.047		0.054
D	8.95		9.35	0.352		0.368
E	10.0		10.28	0.393		0.405
G	4.88		5.28	0.192		0.208
L	15.0		15.85	0.590		0.624
L2	1.27		1.40	0.050		0.055
L3	1.40		1.75	0.055		0.069
R		0.40			0.016	

TO-220F

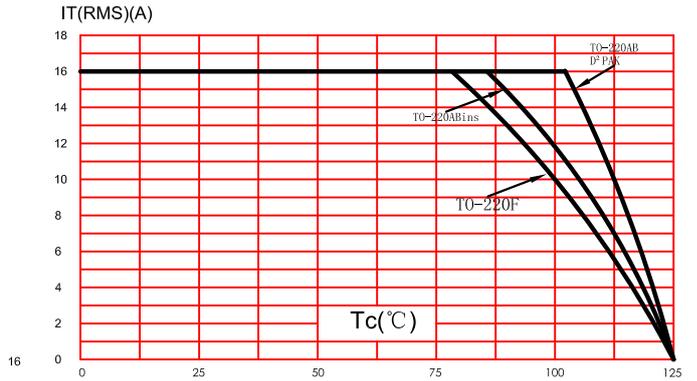


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.4		4.8	0.173		0.189
B	0.74	0.8	0.83	0.029	0.031	0.033
C	0.5		0.75	0.020		0.030
C2	2.4		2.7	0.094		0.106
C3	2.6		3.0	0.102		0.118
D	8.8		9.3	0.346		0.367
E	9.7		10.3	0.382		0.406
F	6.4		6.8	0.252		0.268
G	5.0		5.2	0.197		0.205
H	28.0		29.8	11.0		11.7
L1		3.63			0.143	
L2	1.14		1.7	0.044		0.067
L3		3.3			0.130	
V1		40°			40°	

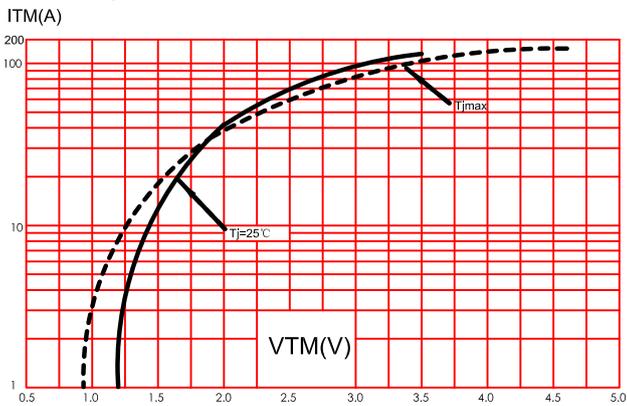
**FIG.1:** Maximum power dissipation versus RMS on-state current(full cycle)



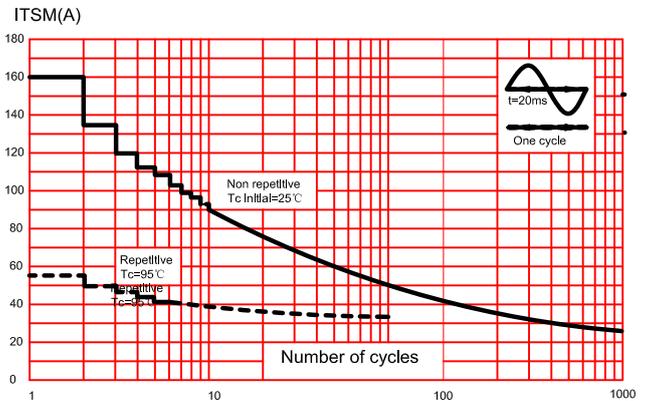
**FIG.2:** RMS on-state current versus case temperature(full cycle)



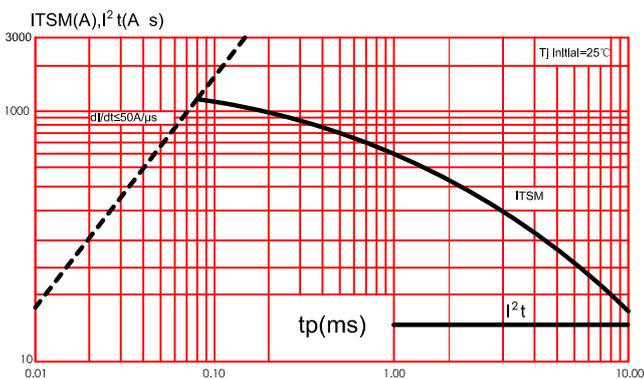
**FIG.3:** On-state characteristics (maximum values)



**FIG.4:** Surge peak on-state current versus number of cycles.



**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10\text{ms}$ , and corresponding value of  $I^2t$



**FIG.6:** Relative variation of gate trigger current, holding current and latching current versus junction temperature(typical values).

